

2.5 mm x 3.2 mm Ceramic Package SMD Oscillator, TTL / HC-MOS



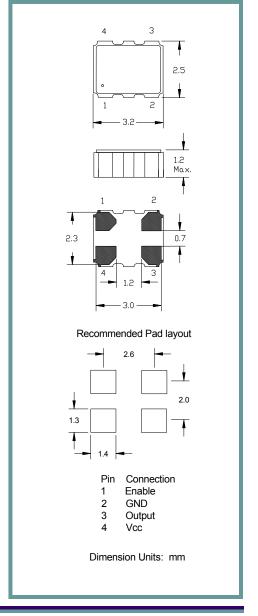
Product Features:

Low Jitter, Non-PLL Based Output CMOS/TTL Compatible Logic Levels Compatible with Leadfree Processing

Applications:

Fibre Channel Server & Storage Sonet /SDH 802.11 / Wifi T1/E1, T3/E3 System Clock

Frequency	1.000 MHz to 152.250 MHz					
Output Level						
HC-MOS	'0' = 0.1 Vcc Max., '1' = 0.9 Vcc Min.					
TTI	'0' = 0.4 VDC Max., '1' = 2.4 VDC Min.					
Duty Cycle	Specify 50% ±10% or ±5% See Table in Part Number Guide					
Duty Cycle	openity 60 % 110 % of 10 % occ Tubic in Fair Namber Guide					
Rise / Fall Time	6 nS Max.					
Output Land	Con Table in Doub Number Ovide					
Output Load	See Table in Part Number Guide					
Frequency Stability See Frequency Stability Table (Includes room temperature tolera						
	stability over operating temperature)					
Start-up Time	10 mS Max.					
Enable / Disable	100 nS Max. N.C. or ≥ 70% Vdd = Enable. ≤ 30% Vdd = Disable.					
Time						
Supply Voltage	See Input Voltage Table, tolerance ±5 %					
Current	25 mA Max. (5.0V)					
	00 4 14 (4 0) 4 0 0) 0					
	20 mA Max. (1.8V-3.3V)					
Operating	See Operating Temperature Table in Part Number Guide					
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Storage	-55° C to +125° C					
Jitter:						
RMS(1sigma)						
1 MHz-60 MHz	5 pS RMS (1 sigma) Max. accumulated jitter (20K adjacent periods)					
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Max Integrated						
1 MHz-60 MHz	1.5 pS RMS (1 sigma -12KHz to 20MHz)					
Max Total Jitter						
1 MHz-60 MHz	50 pS p-p (100K adjacent periods)					
I IVITIZ-OU IVITIZ	30 p3 p-p (100K aujacent penous)					



Part Number Guide		Sample Part Number: ISM97 - 3251BH - 20.0			- 20.000		
Package	Input Voltage	Operating Temperature	Symmetry (Duty Cycle)	Output	Stability (in ppm)	Enable / Disable	Frequency
	5 = 5.0 V	1 = 0° C to +70° C	5 = 45 / 55 Max.	1 = 10TTL / 15 pF HC-MOS	**E = ±10	H = Enable	
ISM97 -	3 = 3.3 V	6 = -10° C to +70° C	6 = 40 / 60 Max.	6 = 30 pF	**D = ±15	O = N/C	
	7 = 3.0 V	3 = -20° C to +70° C		5 = 50 pF HC-MOS (<40 MHz)	**F = ±20		00 000 1411
	2 = 2.7 V	4 = -30° C to +75° C			**A = ±25		- 20.000 MHz
	6 = 2.5 V	2 = -40° C to +85° C			B = ±50		
	1 = 1.8 V*				C = ±100		

NOTE: A 0.01 µF bypass capacitor is recommended between Vcc (pin 4) and GND (pin 2) to minimize power supply noise.

* Not available at all frequencies. ** Not available for all temperature ranges. *** Frequency, supply, and load related parameters.

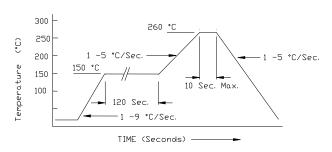


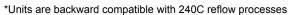


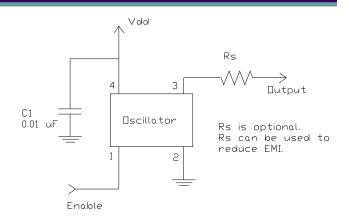
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Pb Free Solder Reflow Profile:

Typical Application:





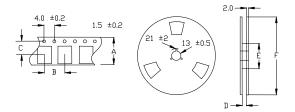


Package Information:

MSL = N.A. (package does not contain plastic, storage life is unlimited under normal room conditions).

Termination = e4 (Au over Ni over W base metalization).

Tape and Reel Information:



Quantity per Reel	1000		
Α	8.0 +/2		
В	4.0 +/2		
С	5.5 +/1		
D	9.0 +/-1		
E	50 / 60 / 80		
F	180		

Environmental Specifications

Thermal Shock	MIL-STD-883, Method 1011, Condition A
Moisture Resistance	MIL-STD-883, Method 1004
Mechanical Shock	MIL-STD-883, Method 2002, Condition B
Mechanical Vibration	MIL-STD-883, Method 2007, Condition A
Resistance to Soldering Heat	J-STD-020C, Table 5-2 Pb-free devices (except 2 cycles max)
Hazardous Substance	Pb-Free / RoHS / Green Compliant
Solderability	JESD22-B102-D Method 2 (Preconditioning E)
Terminal Strength	MIL-STD-883, Method 2004, Test Condition D
Gross Leak	MIL-STD-883, Method 1014, Condition C
Fine Leak	MIL-STD-883, Method 1014, Condition A2, R1=2x10-8 atm cc/s
Solvent Resistance	MIL-STD-202, Method 215

Marking

Line 1: ILSI, Date Code (YWW)

Line 2: Frequency